NSN 5961-00-882-8749

Semiconductor Device Set - Page 1 of 1



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Glass all semiconductor device diode

Overall Length:

0.270 inches all semiconductor device diode

Terminal Length:

1.100 inches all semiconductor device diode

Overall Diameter:

0.104 inches all semiconductor device diode

Internal Configuration:

Junction contact all semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

4 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

600.0 regulator voltage all semiconductor device diode

Current Rating Per Characteristic:

100.00 microamperes source cutoff current horsepower metric all semiconductor device diode

Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction all semiconductor device diode

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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